

# CHCRUS

This is the accepted manuscript made available via CHORUS. The article has been published as:

# Stochastic model of nanomechanical electron shuttles and symmetry breaking

Mo Zhao and Robert H. Blick Phys. Rev. E **93**, 063306 — Published 14 June 2016 DOI: 10.1103/PhysRevE.93.063306

# A Stochastic Model of Nanomechanical Electron Shuttles and Symmetry Breaking

Mo Zhao<sup>1</sup> and Robert H. Blick<sup>1,2,3,\*</sup>

<sup>1</sup>Department of Electrical & Computer Engineering, University of Wisconsin-Madison, Wisconsin 53706, USA

<sup>3</sup>Institutes for Nanostructure and Solid State Physics, University of Hamburg, 20355 Hamburg, Germany

Nanomechanical electron shuttles can work as ratchets for radio-frequency rectification. We develop a full stochastic model of coupled shuttles, where the mechanical motion of nanopillars and the incoherent electronic tunneling are modeled by a Markov chain. In particular, the interaction of their randomness is taken into account, so that a linear master equation is constructed. Numerical solution from our fast approximate method and analytical derivation reveal the symmetry breaking, which results in the direct current observed in earlier measurements [Phys. Rev. Lett. **105**, 067204 (2010)]. Additionally, the method can facilitate device simulation of more complex designs such as shuttle arrays.

#### I. INTRODUCTION

Nanoelectromechanical systems have attracted significant interest in the past decade as they can provide a number of promising applications [1]. Among them, the nanomechanical electron shuttle proposed by Gorelik et al. is an outstanding example that received considerable theoretical [2-22] and experimental [23-34] attention. The shuttle is typically realized by metallic islands, quantum dots, or large molecules, and can be excited by a radio-frequency (RF) voltage so that electrons are shuttled between electrodes. Due to strong nonlinear electro-mechanical coupling, such devices can be used as RF modulators or as high-frequency current ratchet. It was shown that single and—more effectively—coupled electron shuttles can rectify applied RF signals and give rise to a direct current that may be used to power electronic devices [21, 22, 31–33]. While previous theoretical studies provide fundamental insight into the physics, we are still unable to make accurate predictions on the device level.

In this paper, we focus on modeling coupled electron shuttles that would greatly favor energy scavenging. As shown in Fig. 1a, the coupled electron shuttles oscillate between the source and drain electrodes with alternating voltage V(t) (additional gate electrodes with constant charges can be applied), triggering nonresonant electron tunneling. The size of shuttles is generally 1–100 nm and they work at room temperature. Fig. 1b shows a typical design where the oscillation of shuttles is restrained by the supporting nanopillars' eigenmodes. Thus, we develop a new model based on the semi-classical stochastic theory that enables analytical and numerical analysis of the device. This is important for designing practical energy-scavengers, where arrays of electron shuttles are coupled to generate an appreciable output current.

Because the incoherent tunneling is dominant in such scenarios [35], the electron tunneling and the shuttle oscillation in the system can be modeled as a continu-



FIG. 1. (a) Coupled nanomechanical electron shuttles, set with electrodes S, D and optionally G1, G2, oscillate under driving voltage and have electrons tunneled. (b) Side-view of a typical design where shuttles are on top of nanopillars.

ous stochastic process. Thus, a semi-classical statistical model is more suitable than the full quantum-mechanical treatments [15-19], which work better for coherent devices. In the following, we develop a linear master equation describing the probability distribution of the electron numbers in the shuttles. Although the probability distribution was widely discussed in previous studies on the single shuttle [2, 3, 8-14], most approaches describe the mechanical oscillation by deterministic variables and their master equation is nonlinear.

Ahn [21] and Prada [22] extended such approaches to pioneer modeling the coupled shuttles. In contrast to some earlier models [6-11, 14], they allow electron numbers in a shuttle to be greater than 1. Our model follows their assumptions, but the linear master equation enables further analytical study. More importantly, we propose the approximate deterministic equations for the mean and deviation of physical quantities, from which we can compute the macroscopic direct current. This brings the large-scale device simulation to a level of acceptable speed and accuracy.

## **II. FULL STOCHASTIC MODEL**

We describe the displacement and velocity of the  $s^{\text{th}}$ shuttle (s = 1, 2) at the time t by random variables  $\tilde{x}_s(t)$ and  $\tilde{v}_s(t)$ , and describe the number of net electrons in the shuttle by the integer-valued random variable  $\tilde{n}_s(t)$ . For simplicity, we write them by vectors  $\tilde{x}(t)$ ,  $\tilde{v}(t)$  and  $\tilde{n}(t)$ 

<sup>&</sup>lt;sup>2</sup>Center for Hybrid Nanostructures, Falkenried 88, 20251 Hamburg, Germany

<sup>\*</sup> robert@nanomachines.com

(typically '(t)' is omitted in the following). We assume these three random variables are sufficient to describe the immediate state of the system and evolute as a Markov chain. The mean of a random variable is noted by a bracket, e.g.,  $\langle \tilde{\boldsymbol{x}}(t) \rangle$  or simply  $\langle \tilde{\boldsymbol{x}} \rangle$ . Also assume constant number of electrons on the gate electrodes noted by vector  $\boldsymbol{n}_{\rm G}$ . We use  $P(\boldsymbol{n}, \boldsymbol{x}, \boldsymbol{v}, t)$  to describe the joint probability distribution function (PDF) of  $\tilde{\boldsymbol{n}}(t)$ ,  $\tilde{\boldsymbol{x}}(t)$  and  $\tilde{\boldsymbol{v}}(t)$ , whose variables  $\boldsymbol{n}, \boldsymbol{x}$  and  $\boldsymbol{v}$  have the same value range as these random variables.

Assuming the  $s^{\text{th}}$  pillar has an eigenfrequency  $\omega_s$ , effective mass  $m_s$ , and damping coefficient  $\gamma_s = \omega_s/Q$  with Q being the quality factor, we have  $\tilde{x}_s(t)$  and  $\tilde{v}_s(t)$  satisfying the following stochastic differential equations:

$$\begin{cases} d\tilde{x}_s/dt = \tilde{v}_s \\ d\tilde{v}_s/dt = -\gamma_s \tilde{v}_s - \omega_s^2 \tilde{x}_s + F_s(\tilde{\boldsymbol{n}}, t)/m_s \end{cases}$$
(1)

where  $F_s$  is the electromagnetic force on the  $s^{\text{th}}$  shuttle and can be approximated as a function of  $\tilde{\boldsymbol{n}}(t)$  and V(t). Since the probability distribution of  $\tilde{\boldsymbol{n}}(t)$  is unknown, we cannot simply solve the equations to describe  $\tilde{x}_s(t)$  and  $\tilde{v}_s(t)$ . Instead, assuming  $P(\boldsymbol{n}, \boldsymbol{x}, \boldsymbol{v}, t)$  changes to  $P(\boldsymbol{n}', \boldsymbol{x}', \boldsymbol{v}', t')$  after infinitesimal time  $\Delta t = t'-t$ , from Eq. (1) that implies deterministic change of motion, we can write the conditional probability in the form of Dirac delta functions:

$$P(x'_s, v'_s, t' | \boldsymbol{n}, \boldsymbol{x}, \boldsymbol{v}, t) = \delta(x'_s - x_s - v_s \Delta t)$$
(2)

$$\cdot \delta \left( v'_s - v_s + [\gamma_s \tilde{v}_s + \omega_s^2 \tilde{x}_s - F_s(\tilde{\boldsymbol{n}}, t)/m_s] \Delta t \right) + o(\Delta t),$$

where  $o(\Delta t)$  denotes a high-order infinitesimal of  $\Delta t$ .

Another mechanism restraining the PDF besides the mechanical motion is the tunneling of electrons, which can be modeled by the orthodox model [6]. The components of n - n' are limited to  $\pm 1$  and 0 for considering single electron tunneling at each step. Technically, we define a vector  $\boldsymbol{\mu}$ , whose components  $\mu_j$  denote the number of electron tunneled through the  $j^{\text{th}}$  junction (j = 1, 2, 3) and can be 0 and  $\pm 1$ . We also define

$$\boldsymbol{T} = \begin{bmatrix} 1 & 0\\ -1 & 1\\ 0 & -1 \end{bmatrix}, \qquad (3)$$

so that  $n = n' - \mu T$  and note its  $j^{\text{th}}$  row by a vector  $T_j$ . The transition probability of  $\mu_j$  electrons tunneling through the  $j^{\text{th}}$  junction is

$$P(\mu_j, t'|\boldsymbol{n}, \boldsymbol{x}, t) = \begin{cases} \Gamma_j^{\pm} \Delta t, & \mu_j = \pm 1, \\ 1 - (\Gamma_j^+ + \Gamma_j^-) \Delta t, & \mu_j = 0, \end{cases}$$
(4)

where

$$\Gamma_j^{\pm}(\boldsymbol{n}, \boldsymbol{x}, t) = \frac{\mathrm{e}^{-\boldsymbol{x} \cdot \boldsymbol{T}_j / \lambda_j}}{q^2 R_j^0} \frac{U_j^{\pm}}{1 - \mathrm{e}^{-U_j^{\pm} / k_{\mathrm{B}} T}}$$
(5)

is the forward/backward (+/-) tunneling rate of electrons through the  $j^{\text{th}}$  junction, wherein  $R_j^0$  is the unperturbed tunneling resistance from the mechanical motions,  $\lambda_j$  is the tunneling wavelength, T is the temperature,  $k_{\rm B}$  is the Boltzmann constant, and  $U_j^{\pm}$  denotes the change of electromagnetic energy due to the tunneling.

The electromagnetic field can be modeled by the partial capacitance matrix due to the geometry that makes the inductance (or variation of the magnetic energy) negligible. Thus, the energy  $E_{\rm C}$  stored in the field should be a homogeneous 2<sup>nd</sup>-order polynomial of the charges  $q\mathbf{n}(t), q\mathbf{n}_{\rm G}$  and the applied voltage V(t), with coefficients associated with the partial capacitance. Comparing the formula of  $E_{\rm C}$  before and after the tunneling, we obtain the unperturbed  $U_i^{\pm}$ :

$$U_j^{\pm}(\boldsymbol{n},t) = -E_j^0 \mp (\boldsymbol{E}^0 \boldsymbol{\Theta}_j) \cdot (\boldsymbol{n} - \boldsymbol{n}_{\rm G} \boldsymbol{B}) \pm q \kappa_j V(t) \quad (6)$$

where  $E_j^0$  is the  $j^{\text{th}}$  component of  $E^0$  (j = 1, 2, 3) denoting the ground-state energies, B is a unitless matrix to describe the effect of gate bias,  $\kappa_j$  is a unitless coefficient representing the number of electrons pumped between the electrodes by an outside voltage source when an electron tunnels through the  $j^{\text{th}}$  junction, satisfying  $\kappa_1 + \kappa_2 + \kappa_3 = 1$ . Their values are determined by the capacitance matrix associated with geometry and material [36]. In addition,  $\Theta_j$  is a constant matrix:

$$\boldsymbol{\Theta}_{1} = \begin{bmatrix} 2 & 1 \\ 0 & -1 \\ 0 & 1 \end{bmatrix}, \quad \boldsymbol{\Theta}_{2} = \begin{bmatrix} -1 & -1 \\ -1 & 1 \\ 1 & 1 \end{bmatrix}, \quad \boldsymbol{\Theta}_{3} = \begin{bmatrix} -1 & 0 \\ 1 & 0 \\ -1 & -2 \end{bmatrix}$$

The electric force on the  $s^{\text{th}}$  shuttle (s = 1, 2) is  $F_s = -\partial E_{\text{C}}/\partial x_s$ . Take the first-order Taylor expansion of  $E_{\text{C}}$  and ignore the dependence of  $F_s$  on  $x_s$ . We get

$$F_{s}(\tilde{\boldsymbol{n}},t) = \tilde{\boldsymbol{n}} \boldsymbol{F}_{s}^{0} \tilde{\boldsymbol{n}}^{\mathrm{T}} + \tilde{\boldsymbol{n}} \boldsymbol{F}_{s}^{\mathrm{G}} \boldsymbol{n}_{\mathrm{G}}^{\mathrm{T}} + \boldsymbol{n}_{\mathrm{G}} \boldsymbol{F}_{s}^{\mathrm{GG}} \boldsymbol{n}_{\mathrm{G}}^{\mathrm{T}} + q(\tilde{\boldsymbol{n}} \cdot \boldsymbol{\alpha}_{s} + \boldsymbol{n}_{\mathrm{G}} \cdot \boldsymbol{\alpha}_{s}^{\mathrm{G}}) V(t), \qquad (7)$$

where  $\mathbf{F}_s^0$ ,  $\mathbf{F}_s^{\mathrm{G}}$  and  $\mathbf{F}_s^{\mathrm{GG}}$  are matrices of constant force related to geometry and material (the matrix dimensions are consistent with their multipliers  $\tilde{\mathbf{n}}$  or  $\mathbf{n}_{\mathrm{G}}$  to make  $F_s$ a scalar), and  $\boldsymbol{\alpha}_s$  and  $\boldsymbol{\alpha}_s^{\mathrm{G}}$  are constant vectors representing the reciprocal length. These parameters result from spatial derivatives of the capacitance matrix. Note that  $\alpha_{ss}$ , the  $s^{\mathrm{th}}$  component of the vector  $\boldsymbol{\alpha}_s$ , is usually much larger than other components. If  $\mathbf{n}_{\mathrm{G}} = 0$ , we could drop the small terms and use  $F_s \cong q\tilde{n}_s \alpha_{ss} V(t)$ , which is linear to  $\tilde{n}_s$  and consistent with the assumption in [21]. For large  $\mathbf{n}_{\mathrm{G}}$ ,  $F_s \cong q\mathbf{n}_{\mathrm{G}} \cdot \boldsymbol{\alpha}_s^{\mathrm{G}} V(t)$  is a fair approximation.

The white noise can be added to Eq. (7) to account for heating effects, but its energy  $k_{\rm B}T/2$  is usually far too small compared to the electric driving vibrations.

For the first-order perturbation for  $\boldsymbol{x}$ ,  $E_{\rm C}$  should be subtracted by  $\boldsymbol{F}(\boldsymbol{n},t) \cdot \boldsymbol{x}$ , where  $\boldsymbol{F} = [F_1, F_2]$  is the force vector on shuttles. For  $\boldsymbol{n}_{\rm G} = 0$ , we have

$$U_j^{\pm}(\boldsymbol{n}, \boldsymbol{x}, t) \cong U_j^{\pm}(\boldsymbol{n}, t) \mp [qV(t)\bar{\boldsymbol{\alpha}}_j + \boldsymbol{n}\bar{\boldsymbol{F}}_j^0] \cdot \boldsymbol{x},$$

where  $\bar{F}_j^0 = [F_1^0 T_j^{\mathrm{T}}, F_2^0 T_j^{\mathrm{T}}], \bar{\alpha}_j = T_j[\alpha_1^{\mathrm{T}}, \alpha_2^{\mathrm{T}}].$  For  $n_{\mathrm{G}} \neq 0$ , we further add  $\mp T_j[F_1^{\mathrm{G}} n_{\mathrm{G}}^{\mathrm{T}}, F_2^{\mathrm{G}} n_{\mathrm{G}}^{\mathrm{T}}] \cdot x$  to  $U_j$ .

Because the electron tunneling through each junction and the mechanical motion of each shuttle are independent, we have the Chapman-Kolmogorov equation [36]:

$$P(\boldsymbol{n}', \boldsymbol{x}', \boldsymbol{v}', t') = \sum_{\mu_j=0,\pm 1} \int P(\boldsymbol{n}, \boldsymbol{x}, \boldsymbol{v}, t) \prod_{j=1}^{3} P(\mu_j, t' | \boldsymbol{n}, \boldsymbol{x}, t)$$
$$\cdot \prod_{s=1}^{2} P(x'_s, v'_s, t' | \boldsymbol{n}, \boldsymbol{x}, \boldsymbol{v}, t) d\Omega, \qquad (8)$$

where  $d\Omega = dx_1 dx_2 dv_1 dv_2$ . From Eq. (2), (4) and (8), we can describe the time derivative of the PDF by adopting the limit  $t' \to t$ . Note that a strict derivation should consider a mixed moment of displacement and velocity instead of using Eq. (2), which is covered by [36]. We hence build the following master equation for P(n, x, v, t):

$$\frac{\partial P}{\partial t} = \sum_{j=1}^{3} \sum_{\pm} \left( \hat{\mathcal{N}}_{\mp T_j} - 1 \right) \Gamma_j^{\pm} P \tag{9}$$

$$+\sum_{s=1}^{2} \left\{ \gamma_s P - v_s \frac{\partial P}{\partial x_s} + \left[ \gamma_s v_s + \omega_s^2 x_s - \frac{F_s(\boldsymbol{n}, t)}{m_s} \right] \frac{\partial P}{\partial v_s} \right\},\,$$

where the operator  $\hat{\mathcal{N}}_{\mp T_i}$  shifts the argument n in a function by  $\mp T_i$ . Eq (9) is a linear first-order partial differential equation. Its boundary condition is implicit, i.e., as  $|n_s| \to \infty$  or  $|x_s| \to \infty$  or  $|v_s| \to \infty$ ,  $P(\boldsymbol{n}, \boldsymbol{x}, \boldsymbol{v}, t) \to 0$ (asymptotically as a Gaussian function). In addition, Eq. (9) is homogeneous, so the solution is linear with the initial condition, in which the PDF should be normalized. Given an initial condition, we can solve the equation to obtain a conditional-PDF. Nevertheless, we are more interested in the steady-state solution in which the PDF becomes periodic and irrelevant to the initial PDF after numerous periods (so that the initial condition only plays a role in normalization). From numerical solutions, we learn that such a PDF (at a specific time) is usually very close to a multivariate Gaussian distribution [36]. This conclusion complies with the central limit theorem under weak dependence, because the stochastic process consists of infinite times of single electron tunneling which are weakly dependent on others.

Although Eq. (9) with linear properties is meaningful for analysis, it is very difficult to solve numerically with good accuracy (like the Monte-Carlo method and the method of lines), because the PDF has as many as seven arguments. Ignoring the generally weak correlation of  $\tilde{\boldsymbol{n}}(t)$  and  $\tilde{\boldsymbol{x}}(t)$  and the relatively small variance of  $\tilde{\boldsymbol{x}}(t)$ , we can integrate Eq. (9) over  $x_1, x_2, v_1, v_2$  to transform into a simpler equation for the marginal distribution  $P(\boldsymbol{n}, t) = \int P(\boldsymbol{n}, \boldsymbol{x}, \boldsymbol{v}, t) d\Omega$ :

$$\frac{\partial P(\boldsymbol{n},t)}{\partial t} = \sum_{j=1}^{3} \sum_{\pm} \left( \hat{\mathcal{N}}_{\mp \boldsymbol{T}_{j}} - 1 \right) \Gamma_{j}^{\pm}(\boldsymbol{n}, \langle \tilde{\boldsymbol{x}} \rangle, t) P(\boldsymbol{n}, t), (10)$$

where  $\langle \tilde{\boldsymbol{x}} \rangle$  can be linked to  $\langle F_s(\tilde{\boldsymbol{n}},t) \rangle$  by the mean of Eq. (1). In fact, this is equivalent to the master equation given in [21] and [22]. The disadvantage is that the

equation is nonlinear as the relation of  $\langle \tilde{x} \rangle$  and P(n,t) is implicit. Without linearity, we can hardly discuss the analytical solution, since superposition of initial conditions and solutions are disallowed. For numerical solutions, challenge is normalization of the PDF and convergence and accuracy after a long time. Besides, the approximation does not cover the resonance scenario where  $\max \langle \tilde{x}(t) \rangle \gg \lambda_j$ .

## **III. DEVICE-LEVEL SIMULATION**

### A. Approximate Solution for Means and Variances

In fact, we are more interested in the measurable physical quantities which are the mean values of the random variables, rather than the PDF. Without solving the PDF, we can build deterministic equations for the mean from Eq. (9) as well and solve them as time-dependent functions. By multiplying  $n_s$  to both side of Eq. (9), s = 1, 2, and summing over n, x, v, we obtain

$$\frac{\mathrm{d}\langle \tilde{n}_s \rangle}{\mathrm{d}t} = \sum_{j=1}^3 T_{js} \langle \Gamma_j(\tilde{\boldsymbol{n}}, \tilde{\boldsymbol{x}}, t) \rangle \tag{11}$$

where  $\Gamma_j = \Gamma_j^+ - \Gamma_j^-$ , and  $T_{js}$  is a matrix element of T. Let us first consider a simple approximation: use the

Let us first consider a simple approximation: use the unperturbed  $\langle U_j^{\pm}(\tilde{\boldsymbol{n}},t)\rangle$  and assume its mean has an absolute value much larger than  $k_{\rm B}T$ ; ignore the correlation of  $\tilde{\boldsymbol{n}}(t)$  and  $\tilde{\boldsymbol{x}}(t)$  and the variance of  $\tilde{\boldsymbol{x}}(t)$ . Then  $\Gamma_j(\tilde{\boldsymbol{n}},t) \approx U_j(\tilde{\boldsymbol{n}},t)/(q^2 R_j^0)$ , where

$$U_j(\tilde{\boldsymbol{n}},t) = [U_j^+(\tilde{\boldsymbol{n}},t) - U_j^-(\tilde{\boldsymbol{n}},t)]/2$$
  
=  $q\kappa_j V(t) - (\tilde{\boldsymbol{n}} - \boldsymbol{n}_{\rm G}\boldsymbol{B}) \cdot (\boldsymbol{E}^0\boldsymbol{\Theta}_j)$ 

is a linear function of  $\tilde{n}$ . We can replace Eq. (11) by

$$\frac{\mathrm{d}\langle \tilde{n}_s \rangle}{\mathrm{d}t} \cong \sum_{j=1}^3 \frac{T_{js}}{q^2 R_j^0} \mathrm{e}^{-\langle \tilde{\boldsymbol{x}} \rangle \cdot \boldsymbol{T}_j / \lambda_j} U_j(\langle \tilde{\boldsymbol{n}} \rangle, t).$$
(12)

This can be combined with the mean of Eq. (1) to solve  $\langle \tilde{x} \rangle$  and  $\langle \Gamma_j \rangle$ . In fact, Eq. (12) can be interpreted as a circuit model composed by capacitors and resistors, and the model can even more be simplified by ignoring the charging current of capacitors (i.e.,  $\partial \langle \tilde{n}_s \rangle / \partial t = 0$ ) to comply with the adiabatic-limit model in [21]. However, this simple circuit model does not hold with a high frequency excitation and is too rough for simulation of the current.

For higher accuracy, we may assume  $\tilde{n}_s$ ,  $\tilde{x}_s$  and  $\tilde{v}_s$ (s = 1, 2) have the multivariate Gaussian distribution. If the covariance matrices of  $\tilde{n}$ ,  $\tilde{x}$  and  $\tilde{v}$  are denoted by D,  $\Lambda$  and V, respectively, we can use the Taylor expansion of  $\Gamma_j^{\pm}(\tilde{n}, \tilde{x}, t)$  for  $\tilde{n}$  and  $\tilde{x}$  near their means to obtain

$$\langle \Gamma_j^{\pm}(\tilde{\boldsymbol{n}}, \tilde{\boldsymbol{x}}, t) \rangle \cong \frac{1}{q^2 R_j^0} \mathrm{e}^{-\langle \tilde{\boldsymbol{x}} \rangle \cdot \boldsymbol{T}_j / \lambda_j} \mathrm{e}^{\boldsymbol{T}_j \boldsymbol{\Lambda} \boldsymbol{T}_j^{\mathrm{T}} / \lambda_j^2}$$
(13)

$$\sum_{l_1,l_2=0}^{\infty} \frac{(\mp 1)^{l_1+l_2}}{l_1! l_2!} E_{1j}^{l_1} E_{2j}^{l_2} \cdot Y_{l_1+l_2} \left( U_j^{\pm}(\langle \boldsymbol{n} \rangle, \langle \boldsymbol{x} \rangle, t) \right) M_{l_1 l_2},$$

where  $Y_l(U) = \partial^l \left[ U/(1 - e^{-U/k_{\rm B}T}) \right] / \partial U^l$ ,  $E_{1j}$  and  $E_{2j}$ are components of  $E^0 \Theta_j$ , and  $M_{l_1 l_2}$  is the  $l_1, l_2$ -order mixed moment of  $n_1, n_2$  following the Isserlis' theorem:

$$M_{l_1 l_2} = \langle (\tilde{n}_1 - \langle \tilde{n}_1 \rangle)^{l_1} (\tilde{n}_2 - \langle \tilde{n}_2 \rangle)^{l_2} \rangle$$
(14)

$$= \begin{cases} \sum_{k=0}^{l_{\rm m}} \frac{l_1! l_2! D_{11}^{\frac{1}{2}-\kappa} D_{22}^{\frac{1}{2}-\kappa}}{(l_1-2k)!! (l_2-2k)!!} \frac{D_{1k}^{2k}}{(2k)!}, & l_1, l_2 \text{ even} \\ \\ \sum_{l_{\rm m}}^{l_{\rm m}} \frac{l_1! l_2! D_{11}^{\frac{1}{2}-\kappa} D_{22}^{\frac{1}{2}-\kappa}}{(2k)!! (l_2-2k)!!} \frac{D_{1k}^{2k}}{(2k)!}, & l_1, l_2 \text{ even} \end{cases}$$

$$\sum_{\substack{k=0\\0,}} \frac{l_1! l_2! D_{11}^2 D_{22}^2}{(l_1 - 1 - 2k)!! (l_2 - 1 - 2k)!!} \frac{D_{12}^{-1}}{(2k+1)!}, \ l_1, l_2 \text{ odd}$$

where  $l_{\rm m}$  denotes the integer part of  $\min(l_1, l_2)/2$ . We can also build equations for the variance and the covariance:

$$\frac{\mathrm{d}D_{ss}}{\mathrm{d}t} = \sum_{j=1}^{3} [2T_{js} \langle \Gamma_j(\tilde{\boldsymbol{n}}, \tilde{\boldsymbol{x}}, t)(\tilde{n}_s - \langle \tilde{n}_s \rangle) \rangle + T_{js}^2 \langle \Gamma_j^*(\tilde{\boldsymbol{n}}, \tilde{\boldsymbol{x}}, t) \rangle], \qquad (15)$$

$$\frac{\mathrm{d}D_{12}}{\mathrm{d}t} = \sum_{j=1}^{3} \sum_{s=1}^{2} T_{j(3-s)} \langle \Gamma_j(\tilde{\boldsymbol{n}}, \tilde{\boldsymbol{x}}, t) (\tilde{n}_s - \langle \tilde{n}_s \rangle) \rangle - \langle \Gamma_2^*(\tilde{\boldsymbol{n}}, \tilde{\boldsymbol{x}}, t) \rangle, \qquad (16)$$

where  $\Gamma_j^* = \Gamma_j^+ + \Gamma_j^-$ . The result of  $\langle \Gamma_j(\tilde{\boldsymbol{n}}, t)(\tilde{n}_s - \langle \tilde{n}_s \rangle) \rangle$ is similar to the right side of Eq. (13) with  $M_{l_1l_2}$  replaced by  $M_{l_1+1,l_2}$  or  $M_{l_1,l_2+1}$  according to s = 1, 2.

Further, assume  $\Sigma_s$  as the covariance of  $\tilde{x}_s$  and  $\tilde{v}_s$ ,  $X_s$  as the covariance of  $\tilde{x}_s$  and  $\tilde{n}_s$ , and  $Y_s$  as the covariance of  $\tilde{n}_s$  and  $\tilde{v}_s$ . Other covariances which are between different shuttles are generally negligible, due to small correlation between  $F_s(\tilde{\boldsymbol{n}},t)$  and  $\tilde{n}_{s'}$  ( $s \neq s'$ ), i.e.,  $\alpha_{ss} \gg \alpha_{ss'}$ . Multiply Eq. (9) with  $x_s$  and  $x_s^2$ , and sum over  $\boldsymbol{n}, \boldsymbol{x}, \boldsymbol{v}$ , so we can derive  $d\langle \tilde{x}_s \rangle/dt = \langle \tilde{v}_s \rangle$  and  $d\langle \tilde{x}_s^2 \rangle/dt = 2\langle \tilde{x}_s \tilde{v}_s \rangle$ , respectively. By combining them, we obtain

$$\frac{\mathrm{d}\Lambda_{ss}}{\mathrm{d}t} = 2\Sigma_s.\tag{17}$$

Similarly, we can build equations describing the time derivative of  $W_s$ ,  $\Sigma_s$ ,  $X_s$ , and  $Y_s$  [36]:

$$\frac{\mathrm{d}W_s}{\mathrm{d}t} = 2\left[-\gamma_s W_s - \omega_s^2 \Sigma_s + Y_s \frac{\langle f_s(\tilde{\boldsymbol{n}}, t) \rangle}{m_s}\right],\qquad(18)$$

$$\frac{\mathrm{d}\Sigma_s}{\mathrm{d}t} = W_s - \gamma_s \Sigma_s - \omega_s^2 \Lambda_{ss} + X_s \frac{\langle f_s(\tilde{\boldsymbol{n}}, t) \rangle}{m_s}, \qquad (19)$$

$$\frac{\mathrm{d}X_s}{\mathrm{d}t} = \sum_{j=1}^3 T_{js} \langle K_j(\tilde{\boldsymbol{x}}) \rangle \left[ g_{js}(t) X_s - \frac{T_{js}}{\lambda_j} G_j(t) \Lambda_{ss} \right] + Y_s,$$
(20)

$$\frac{\mathrm{d}V_{ss}}{\mathrm{d}t} = \sum_{j=1}^{3} T_{js} \langle K_j(\tilde{\boldsymbol{x}}) \rangle \left[ g_{js}(t) Y_s - \frac{T_{js}}{\lambda_j} G_j(t) \Sigma_s \right] - \gamma_s Y_s - \omega_s^2 X_s + \frac{\langle F_s(\tilde{\boldsymbol{n}}, t)(\tilde{n}_s - \langle \tilde{n}_s \rangle) \rangle}{m_s}, \quad (21)$$

where we define  $f_s(\boldsymbol{n},t) = \partial F_s(\boldsymbol{n},t)/\partial n_s$  which is a linear function of  $\boldsymbol{n}$ ,  $K_j(\tilde{\boldsymbol{x}}) = e^{-\tilde{\boldsymbol{x}}\cdot\boldsymbol{T}_j/\lambda_j}$  and its mean  $\langle K_j(\tilde{\boldsymbol{x}}) \rangle = K_j(\langle \tilde{\boldsymbol{x}} \rangle) e^{\boldsymbol{T}_j \boldsymbol{\Lambda} \boldsymbol{T}_j^{\mathrm{T}}/\lambda_j^2}$ ,  $\boldsymbol{g}_j(t) = \langle \partial \Gamma_j(\tilde{\boldsymbol{n}},t)/\partial \tilde{\boldsymbol{n}} \rangle$  with  $g_{js}(t)$  being the s<sup>th</sup> component, and  $G_j(t) = \langle \Gamma_j(\tilde{\boldsymbol{n}},t) \rangle - \boldsymbol{g}_j(t) \mathrm{diag}(\boldsymbol{T}_j)[X_1, X_2]^{\mathrm{T}}/\lambda_j.$ 

The model can be further refined by the nonlinear resistance and the nonlinear vibration of nanopillars. According to the calculation in [37], we can add a factor of  $(1 + \beta_j U_j^2)$  to the conductance  $1/R_j^0$  in Eq. (5), where  $\beta \propto (d_j/\lambda_j)^2$  if the tunneling length  $d_j \gg \lambda_j$ .

We can combine the ordinary differential equations Eq. (11),(13)-(21) and the mean of Eq. (1) together in order to solve the mean of variables, which can be accomplished numerically. Empirically, the order of moment in Eq. (14) can be set to  $l_1 + l_2 \leq 4$  for decent accuracy. For nonresonant scenarios, we can simply set  $\Lambda_{ss}$ ,  $W_s$ ,  $\Sigma_s$ ,  $X_s$  and  $Y_s$  zero and ignore Eq. (17)-(21) to reduce the complexity. Another considerable approximation is that a high quality factor Q for the mean of Eq. (1) may be scaled down to a smaller value by scaling up  $\lambda_j$ , in order to greatly reduce the simulation time, as long as vibration is close to an undamped resonance (the resonant frequency is close to the eigenfreuency, the electric force is usually balanced by the damping force in the steady state). Details are discussed in [36].

#### B. Current

The macroscopic current can be calculated from the mean rate of electrons tunneling:

$$I(t) = C_0 \frac{\mathrm{d}V}{\mathrm{d}t} + q \sum_{j=1}^{3} \kappa_j \langle \Gamma_j(\tilde{\boldsymbol{n}}, \tilde{\boldsymbol{x}}, t) \rangle, \qquad (22)$$

where  $C_0$  is the equivalent capacitance seen from the electrode. In the steady state, I(t) is periodic. Direct current  $I_{\rm dc}$  is a time-average of I(t) for a full period. As  $\langle \tilde{n}_1 \rangle$ ,  $\langle \tilde{n}_2 \rangle$  and V(t) are periodic, we can substitute Eq. (11) into Eq. (22) and remove the terms with  $\partial \langle \tilde{n}_{1,2} \rangle / \partial t$ , thus

$$I_{\rm dc} = \frac{q\omega}{2\pi} \int_{t_0}^{t_0 + 2\pi/\omega} \langle \Gamma_j(\tilde{\boldsymbol{n}}, \tilde{\boldsymbol{x}}, t) \rangle {\rm d}t, \qquad (23)$$

where j = 1,2 or 3 are equal. The value of  $I_{\rm dc}$  is usually small compared to I(t) because the current flows in another direction after half a period  $\pi/\omega$ .

An important conclusion about symmetry breaking of the current can be derived from Eq. (9). If  $\mathbf{n}_{\rm G} = 0$ and  $V(t) = -V(t + \pi/\omega)$ , we have  $\Gamma_j^{\pm}(\mathbf{n}, \mathbf{x}, t + \pi/\omega) =$  $\Gamma_j^{\mp}(-\mathbf{n}, \mathbf{x}, t)$  from Eq. (5) and (6), and  $F_s(\mathbf{n}, t + \pi/\omega) =$  $F_s(-\mathbf{n}, t)$  from Eq. (7). Let us replace t by  $t + \pi/\omega$  in Eq. (9), and substitute the above relations into Eq. (9) with  $\mathbf{n}$  replaced by  $-\mathbf{n}$ . Then, we obtain the same equation for  $P(-\mathbf{n}, \mathbf{x}, \mathbf{v}, t + \pi/\omega)$  as Eq. (9) indicating  $P(\mathbf{n}, \mathbf{x}, \mathbf{v}, t), P(-\mathbf{n}, \mathbf{x}, \mathbf{v}, t + \pi/\omega) = P(\mathbf{n}, \mathbf{x}, \mathbf{v}, t)$  in the steady-state solution. In this case, we have I(t) = $-I(t + \pi/\omega)$  from Eq. (22) and no direct current.



FIG. 2. Direct current versus driving frequency (with an offset of the average eigenfrequency of the two shuttles 500 MHz), when driving amplitude is 1 V and a second-order harmonic with amplitude of 0.5 V introduces asymmetry. The difference of two eigenfrequencies are varied for 3 curves, indicated in the legend.

Thus, there are two ways to break the symmetry: First is to apply bias on the gate. If  $\mathbf{n}_{\rm G} \neq 0$ , we still have  $\Gamma_j^{\pm}(\mathbf{n}, t+\pi/\omega) = \Gamma_j^{\mp}(2\mathbf{n}_{\rm G}\mathbf{B}-\mathbf{n}, t)$ , but  $F_s(\mathbf{n}, t+\pi/\omega) \neq$  $F_s(2\mathbf{n}_{\rm G}\mathbf{B}-\mathbf{n}, t)$ . Thus,  $I(t) \neq -I(t+\pi/\omega)$  which enables the direct current. Second is to introduce even-order harmonics in V(t), which breaks the symmetry of AC voltage after half a period making  $V(t) \neq -V(t+\pi/\omega)$ . The wave superposition makes use of the nonlinear transport relation. In practice, this could be realized by natural wave distortion, introducing nonlinear elements in the circuit, or magnifying the second-order harmonic by RF circuit.

In addition, as  $e^{-\langle \boldsymbol{x} \rangle \cdot T_j / \lambda_j}$  is periodic with  $\omega$ ,  $\langle \tilde{\boldsymbol{n}}(t) \rangle$  has considerable higher-order harmonic components. Thus, the system resonates when the frequency component is close to both  $\omega_1$  and  $\omega_2$ , so  $\omega$  should be around  $\omega_1/l$ where  $l = 1, 2, 3, \ldots$ , and smaller l leads to stronger vibrations. This phenomenon is known as Arnold's tongues and was observed in [31, 32].

The direct current, as a key device characteristic, must be obtained from accurate numerical computation, since the value is usually so small that it is flooded by noise, and therefore it can hardly be acquired from previous methods. Using our fast approximate solution above, Fig. 2 plots a typical resonant response of coupled shuttles, whose geometry follows [31] (for simulation of capacitance and resistance) and their eigenfrequencies are both around 500 MHz. Here we assume that V(t) = $V_1 \sin(\omega t) + V_2 \cos(2\omega t)$  with  $V_1 = 1$  V and  $V_2 = 0.5$  V. The second order harmonics (with  $\pi/2$  phase difference) introduces asymmetric phases for current of two directions. According to theoretical prediction [37] and to match experimental results in [31], we assume the tunneling length  $\lambda_j$  is 0.2 Å.

In addition, Fig. 3 shows how the amplitude of driving voltage impacts on the direct current, where  $V_1$  varies from 0 to 2 V and  $V_2/V_1$  varies from 0.2 to 0.5. The quasi-



FIG. 3. Peak direct current (over the frequency) versus driving voltage amplitude  $V_1$ , with different ratios of second-order amplitude  $V_2/V_1$ .

inear reation matches the measurement in [31]. Although the direct current shown here is of the order of 10 pA,  $10^9$  arrays integrated in 1 cm<sup>2</sup> area could provide a 10 mA order current, which is useful to drive a device.

#### IV. CONCLUSION

In conclusion, we have proposed a full stochastic model for the coupled nanomechanical electron shuttles, focusing on the Markovian behavior and the direct output current. By treating the electronic and mechanical motions as stochastic processes, we derive the linear master equation that enables analysis of symmetry breaking. Further results show that even-order harmonics of the driving voltage or a gate bias are necessary for observing a direct signal. Beyond, we developed the deterministic ordinary differential equations for the mean and covariance of random variables, by assuming the multivariate Gaussian distribution. This provides an efficient method for device-level simulation.

#### ACKNOWLEDGMENTS

We acknowledge support by the Wisconsin Alumni Research Foundation (WARF) through an Accelerator grant and the Defense Advanced Research Projects Agency (DARPA) through the NEMS-CMOS program (N66001-07-1-2046).

- O. Y. Loh and H. D. Espinosa, Nature Nanotech. 7, 283 (2012).
- [2] L. Y. Gorelik, A. Isacsson, M. V. Voinova, B. Kasemo, R. I. Shekhter, and M. Jonson, Phys. Rev. Lett. 80, 4526

- [3] C. Weiss and W. Zwerger, Europhys. Lett. 47, 97 (1999).
- [4] N. Nishiguchi, Phys. Rev. B **65**, 035403 (2001).
- [5] A. Isacsson and T. Nord, Europhys. Lett. 66, 708 (2004).
- [6] A. D. Armour, M. P. Blencowe, and Y. Zhang, Phys. Rev. B 69, 125313 (2004).
- [7] A. D. Armour, Phys. Rev. B 70, 165315 (2004).
- [8] F. Pistolesi and R. Fazio, Phys. Rev. Lett. 94, 036806 (2005).
- [9] F. Pistolesi and R. Fazio, New J. Phys. 8, 113 (2006).
- [10] C. Huldt and J. M. Kinaret, New J. Phys. 9, 51 (2007).
- [11] N. Nishiguchi, Phys. Rev. B 78, 085407 (2008).
- [12] L. M. Jonsson, F. Santandrea, L. Y. Gorelik, R. I. Shekhter, and M. Jonson, Phys. Rev. Lett. **100**, 186802 (2008).
- [13] J. Wiersig, S. Flach, and K.-H. Ahn, Appl. Phys. Lett. 93, 222110 (2008).
- [14] M. E. Pena-Aza, A. Scorrano, and L. Y. Gorelik, Phys. Rev. B 88, 035412 (2013).
- [15] D. Fedorets, L. Y. Gorelik, R. I. Shekhter, and M. Jonson, Phys. Rev. Lett. **92**, 166801 (2004).
- [16] T. Novotny, A. Donarini, and A.-P. Jauho, Phys. Rev. Lett. 90, 256801 (2003).
- [17] T. Novotny, A. Donarini, C. Flindt, and A.-P. Jauho, Phys. Rev. Lett. **92**, 248302 (2004).
- [18] Z. Rong, C. Wei-Dong, D. Su-Qing, and Y. Ning, Chinese Physics B 22, 117305 (2013).
- [19] S. I. Kulinich, L. Y. Gorelik, A. N. Kalinenko, I. V. Krive, R. I. Shekhter, Y. W. Park, and M. Jonson, Phys. Rev. Lett. **112**, 117206 (2014).
- [20] M. J. Moeckel, D. R. Southworth, E. M. Weig, and F. Marquardt, New J. Phys. 16, 043009 (2014).

- [21] K. H. Ahn, H. C. Park, J. Wiersig, and H. Jongbae, Phys. Rev. Lett. 97, 216804 (2006).
- [22] M. Prada and G. Platero, Phys. Rev. B 86, 165424 (2012).
- [23] A. Erbe, R. H. Blick, A. Tilke, A. Kriele, and J. P. Kotthaus, Appl. Phys. Lett. 73, 3751 (1998).
- [24] H. Park, J. Park, A. K. L. Lim, E. H. Anderson, A. P. Alivisotos, and P. L. McEuen, Nature 407, 57 (2000).
- [25] A. Erbe, C. Weiss, W. Zwerger, and R. H. Blick, Phys. Rev. Lett. 87, 096106 (2001).
- [26] D. V. Scheibe and R. H. Blick, Appl. Phys. Lett. 84, 4632 (2004).
- [27] D. R. Koenig, E. M. Weig, and J. P. Kotthaus, Nature Nanotech 3, 482 (2008).
- [28] D. V. Scheible and R. H. Blick, New J. Phys. **12**, 023019 (2010).
- [29] D. R. Koenig and E. M. Weig, Appl. Phys. Lett. 101, 213111 (2012).
- [30] H. S. Kim, H. Qin, and R. H. Blick, New J. Phys. 12, 033008 (2010).
- [31] C. Kim, J. Park, and R. H. Blick, Phys. Rev. Lett. 105, 067204 (2010).
- [32] C. Kim, M. Prada, and R. H. Blick, ACS Nano 6, 651 (2012).
- [33] C. Kim, M. Prada, G. Platero, and R. H. Blick, Phys. Rev. Lett. **111**, 197202 (2013).
- [34] C. Kim, M. Prada, H. Qin, H.-S. Kim, and R. H. Blick, Appl. Phys. Lett. **106**, 061909 (2015).
- [35] R. I. Shekhter, L. Y. Gorelik, M. Jonson, Y. M. Galperin, and V. M. Vinokur, J. Comput. Theor. Nanosci. 4, 860 (2007).
- [36] M. Zhao and R. H. Blick, arXiv: 1405.1645 (2014).
- [37] J. G. Simmons, J. Appl. Phys. 34, 238 (1963).